## NSN 5961-01-067-3576

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-067-3576 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.096 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 2.20 milliamperes zero-gate-voltage source current any acceptable **Power Rating Per Characteristic:** 0.6 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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